

**isc Silicon PNP Darlingtion Power Transistor**

**PMD17K100**

**DESCRIPTION**

- High DC current gain
- Collector-Emitter Sustaining Voltage-  
 $V_{CEO(SUS)} = -100V(\text{Min})$
- Complement to type PMD16K100

**APPLICATIONS**

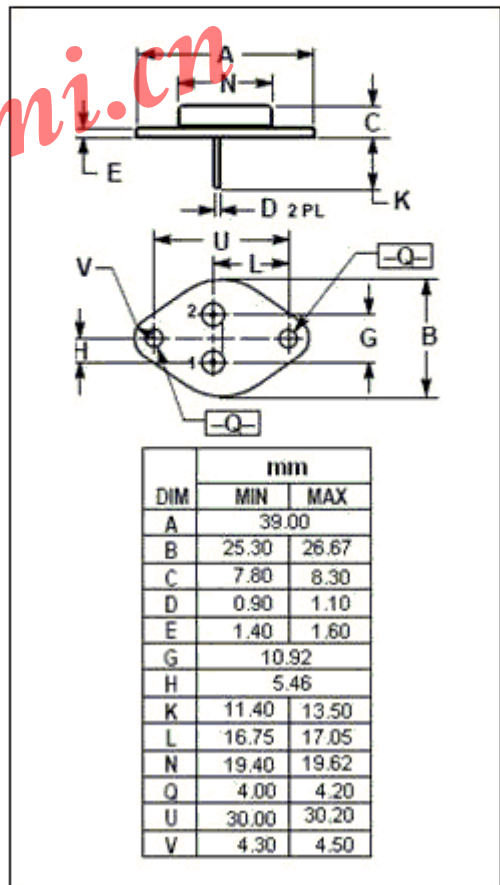
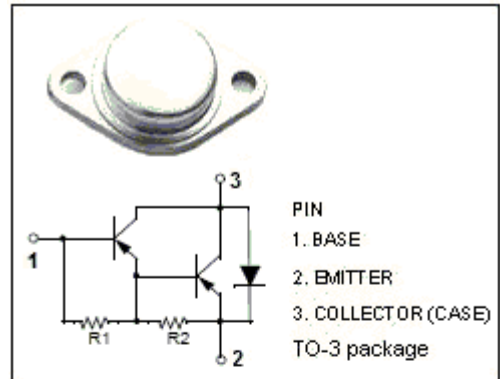
- Designed for general purpose amplifier and low frequency switching applications

**ABSOLUTE MAXIMUM RATINGS( $T_C=25^\circ\text{C}$ )**

SYMBOL	PARAMETER	VALUE	UNIT
$V_{CBO}$	Collector-Base Voltage	-100	V
$V_{CEO}$	Collector-Emitter Voltage	-100	V
$V_{EBO}$	Emitter-Base Voltage	-5.0	V
$I_C$	Collector Current -Continuous	-20	A
$I_{CP}$	Collector Current-Peak	-40	A
$I_B$	Base Current	-0.5	A
$P_C$	Collector Power Dissipation@ $T_C=25^\circ\text{C}$	200	W
$T_j$	Junction Temperature	150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature	-65~200	$^\circ\text{C}$

**THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	MAX	UNIT
$R_{th\ j-c}$	ThermalResistance, Junction to Case	0.875	$^\circ\text{C/W}$



**isc Silicon PNP Darlington Power Transistor****PMD17K100****ELECTRICAL CHARACTERISTICS** $T_C=25^\circ\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
$V_{CE(SUS)}$	Collector-Emitter Sustaining Voltage	$I_C = -100\text{mA}; I_B = 0$	-100		V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = -10\text{A}; I_B = -40\text{mA}$		-2.0	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = -10\text{A}; I_B = -40\text{mA}$		-2.8	V
$V_{BE(on)}$	Base-Emitter On Voltage	$I_C = -10\text{A}; V_{CE} = -3\text{V}$		-2.8	V
$I_{CER}$	Collector Cutoff current	$V_{CE} = -100\text{V}; R_{BE} = 1\text{K}\Omega$ $V_{CE} = -100\text{V}; R_{BE} = 1\text{K}\Omega, T_C = 150^\circ\text{C}$		-1.0 -5.0	mA
$I_{EBO}$	Emitter Cut-off current	$V_{EB} = -5\text{V}; I_C = 0$		-2.0	mA
$h_{FE}$	DC Current Gain	$I_C = -10\text{A}; V_{CE} = -3\text{V}$	800	20000	
$f_T$	Current-Gain—Bandwidth Product	$I_C = -7\text{A}; V_{CE} = -3\text{V}, f = 1\text{kHz}$	4		MHz
$C_{OB}$	Output Capacitance	$I_E = 0; V_{CB} = -10\text{V}; f_{test} = 1.0\text{MHz}$		400	pF